



DMN1014UFDF

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
401/	16mΩ @ V _{GS} = 4.5V	8.0A
12V	25mΩ @ V _{GS} = 2.5V	6.5A

Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- **Battery Management Application**
- **Power Management Functions**
- **DC-DC Converters**

Low Gate Threshold Voltage Fast Switching Speed Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

PCB Footprint of 4mm²

Features

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Halogen and Antimony Free. "Green" Device (Note 3)

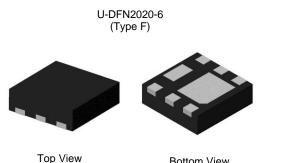
0.6mm Profile - Ideal for Low Profile Applications

For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

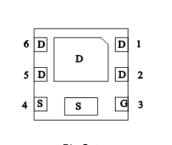
12V N-CHANNEL ENHANCEMENT MODE MOSFET

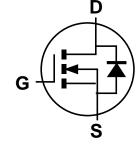
Mechanical Data

- Case: U-DFN2020-6 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)



Bottom View





Pin Out **Bottom View**

Internal Schematic

Ordering Information (Note 4)

Part Number	Reel Size (inches)	Case	Quantity per Reel
DMN1014UFDF-7	7	U-DFN2020-6 (Type F)	3,000
DMN1014UFDF-13	13	U-DFN2020-6 (Type F)	10,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

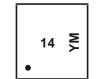
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information

Site 1



14 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2017		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	E		Н		J	K	L	М	N	0	Р	R
	1	1										
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



14 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2017	 2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	7	 0	1	2	3	4	5	6	7	8	9

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	Х	Y	Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	12	V
Gate-Source Voltage			Vgss	±8	V
Continuous Drain Current, V _{GS} = 4.5V (Note 6)	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	8 6	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 16	%)		I _{DM}	40	А
Continuous Source-Drain Diode Current (Note 6)		T _A = +25°C	ls	2.1	А
Pulsed Source-Drain Diode Current (380µs Pulse, I	Duty Cycle = 1%)	lsм	40	А
Avalanche Current, L = 0.1mH (Note 7)	I _{AS}	10.8	А		
Avalanche Energy, L = 0.1mH (Note 7)	Eas	5.8	mJ		

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Dower Dissinction (Nato 5)	T _A = +25°C	D-	0.7	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.4	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	177	°C/W
Tatal Dawan Dissinction (Nata C)	T _A = +25°C	D	1.7	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	1.0	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	76	°C/W
Thermal Resistance, Junction to Case (Note 6)		Rejc	15.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Tun	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Symbol	IVIIII	Тур	IVIAX	Unit	Test condition
· · · · ·	D) (40			14	
Drain-Source Breakdown Voltage	BVDSS	12	_		V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	—	_	1	μA	$V_{DS} = 9.6V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—		±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	Vgs(th)	0.3		1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Bacian		12	16	mΩ	VGS = 4.5V, ID = 2A
Static Drain-Source On-Resistance	RDS(ON)	_	16	25	11122	VGS = 2.5V, ID = 2A
Diode Forward Voltage	V _{SD}	-	0.72	1.2	V	$V_{GS} = 0V, I_S = 2A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	515	—		
Output Capacitance	Coss	—	155	—	pF	$V_{DS} = 6V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	121	—		
Gate Resistance	Rg	—	2.4	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	6.4	—		
Gate-Source Charge	Q _{gs}	—	0.3	—	nC	$V_{DS} = 6V, I_D = 2A$
Gate-Drain Charge	Q _{gd}	—	1.9	—		
Turn-On Delay Time	tD(ON)	—	3.0	—		
Turn-On Rise Time	t _R	—	3.6	—	20	$V_{DS} = 6V, V_{GS} = 4.5V,$
Turn-Off Delay Time	td(off)	—	12.4	—	ns	$R_g = 2\Omega, I_D = 2A$
Turn-Off Fall Time	tF	—	4.4	—		
Reverse Recovery Time	trr	_	9.5	—	ns	IF = 2A, di/dt = 200A/µs
Reverse Recovery Charge	Q _{RR}	_	1.7	_	nC	IF = 2A, di/dt = 200A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

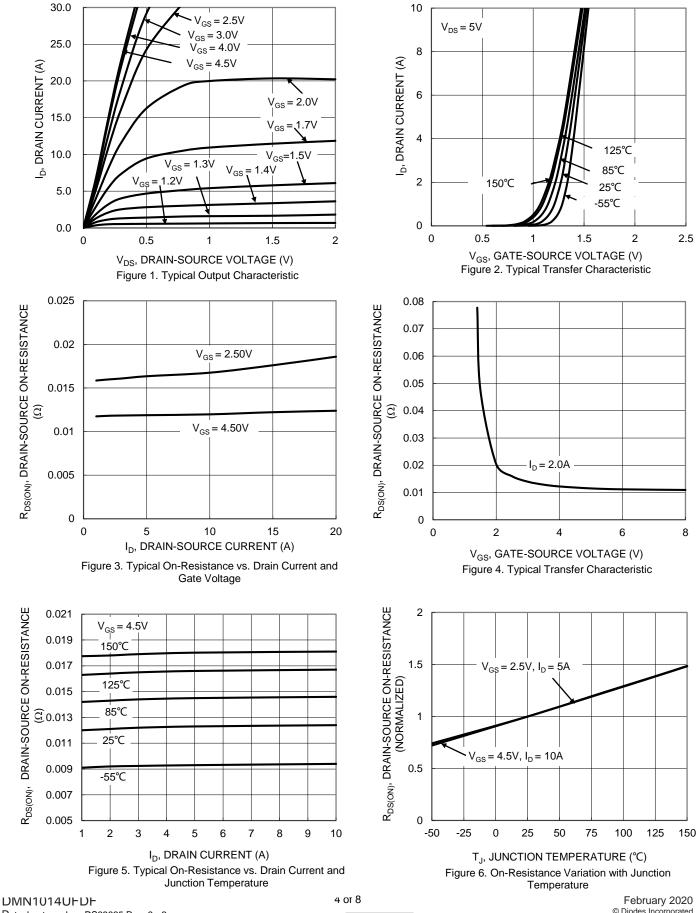
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

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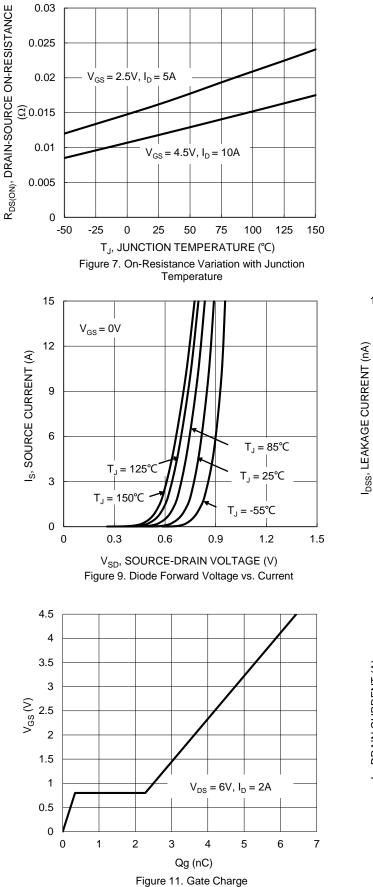
Datasheet number: DS39825 Rev. 3 - 2

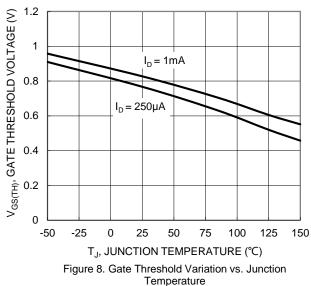
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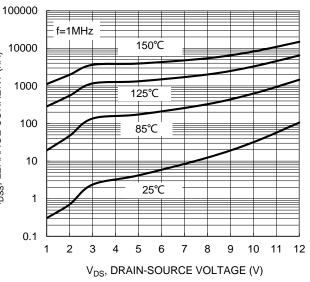


Figure 10. Typical Drain-Source Leakge Current vs Voltage

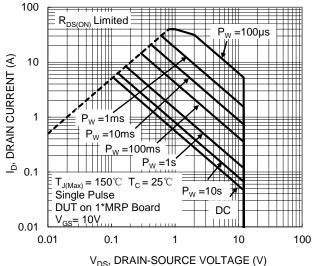
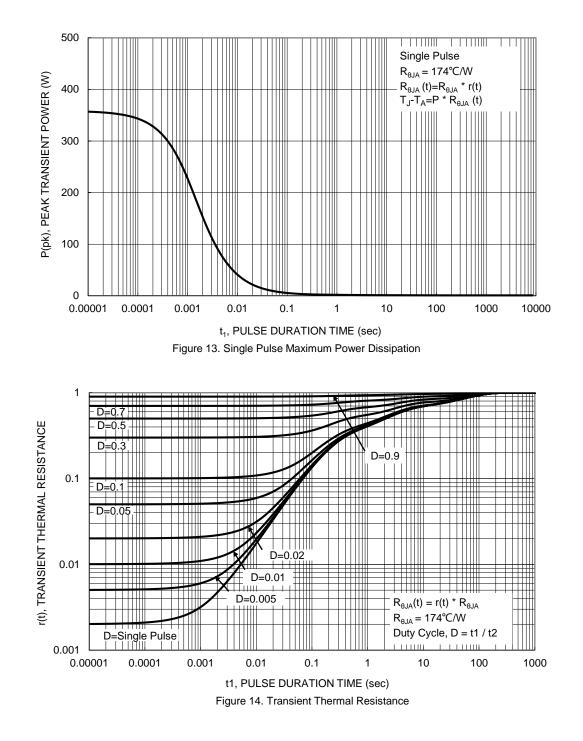


Figure 12. SOA, Safe Operation Area

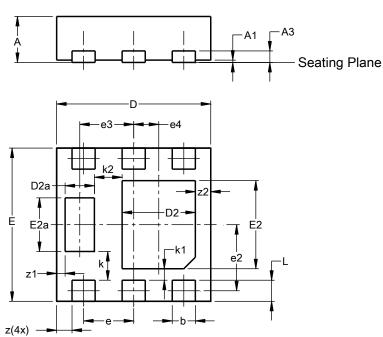






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

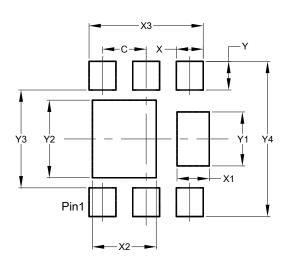


	U-DFN2020-6 (Type F)						
Dim	Min	Max	Тур				
Α	0.57	0.63	0.60				
A1	0.00	0.05	0.03				
A3	-	-	0.15				
b	0.25	0.35	0.30				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
D2a	0.33	0.43	0.38				
E	1.95	2.05	2.00				
E2	1.05	1.25	1.15				
E2a	0.65	0.75	0.70				
е		0.65 BS	С				
e2	0).863 BS	SC				
e3		0.70 BS	С				
e4	().325 BS	SC				
k		0.37 BS	С				
k1		0.15 BS					
k2		0.36 BS	С				
L		0.325					
z		0.20 BS					
z1).110 BS					
z2		0.20 BS					
	Dimens	ions in	mm				

U-DFN2020-6 (Type F)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type F)

Dimensions	Value		
Dimensions	(in mm)		
С	0.650		
Х	0.400		
X1	0.480		
X2	0.950		
X3	1.700		
Y	0.425		
Y1	0.800		
Y2	1.150		
Y3	1.450		
Y4	2.300		



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